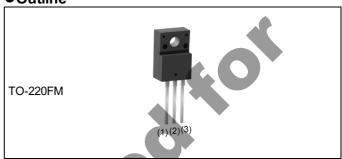
Nch 600V 30A Power MOSFET

V_{DSS}	600V
R _{DS(on)} (Max.)	0.150Ω
I _D	±30A
P _D	90W

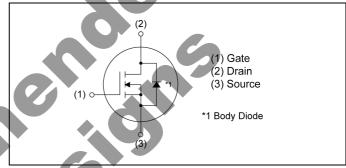
Outline



Features

- 1) Fast reverse recovery time (trr).
- 2) Low on-resistance.
- 3) Fast switching speed.
- 4) Gate-source voltage (V_{GSS}) guaranteed to be ±30V.
- 5) Drive circuits can be simple.
- 6) Pb-free plating; RoHS compliant

●Inner circuit



● F acha	July specifications	
1	Packing	Bulk
	Reel size (mm)	-
Time	Tape width (mm)	-
Type	Basic ordering unit (pcs)	500
	Taping code	-
	Marking	R6030MNX

Application

Switching Power Supply

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	600	V
Continuous drain current (T _c = 25°C)	I _D *1	±30	А
Pulsed drain current	I _{DP} *2	±90	А
Gate - Source voltage	V _{GSS}	±30	V
Avalanche current, single pulse	I _{AS}	5.0	А
Avalanche energy, single pulse	E _{AS}	6.7	mJ
Power dissipation (T _c = 25°C)	P _D	90	W
Junction temperature	T _j	150	°C
Operating junction and storage temperature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Daramatar	Cumbal	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R _{thJC}	-	-	1.38	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	70	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-		265	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V
		$V_{DS} = 600V, V_{GS} = 0V$				
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	-	100	μΑ
		$T_j = 125^{\circ}C$	ı	-	-	
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$	ı	-	±100	nA
Gate threshold voltage	V _{GS(th)}	$V_{DS} = 10V, I_D = 470 \mu A$	3.0	-	5.0	٧
40		V _{GS} = 10V, I _D = 15A				
Static drain - source on - state resistance	R _{DS(on)} *3	T _j = 25°C	-	0.110	0.150	Ω
		$T_j = 125^{\circ}C$	-	-	-	
Gate resistance	R_{G}	f = 1MHz, open drain	-	1.7	-	Ω

● Electrical characteristics (T_a = 25°C)

Davamatar	Cymah al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Uniil
Forward Transfer Admittance	Y _{fs} *3	V _{DS} = 10V, I _D = 15A	7.0	-	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	2180		
Output capacitance	C _{oss}	V _{DS} = 25V	-	2260		pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	30	-	
Turn - on delay time	t _{d(on)} *3	$V_{DD} \simeq 300V$, $V_{GS} = 10V$	-	40	-	
Rise time	t _r *3	I _D = 15A	16	60	-	no
Turn - off delay time	t _{d(off)} *3	$R_L \simeq 20\Omega$	-	70	-	ns
Fall time	t _f *3	$R_G = 10\Omega$	-	20	-	

● Gate charge characteristics (T_a = 25°C)

Darameter	Cumbal	Conditions		Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*3}	V _{DD} ≈ 300V	-	43	-	
Gate - Source charge	Q _{gs} *3	I _D = 30A	-	15	-	nC
Gate - Drain charge	Q _{gd} *3	V _{GS} = 10V	-	13	-	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq 300V$, $I_D = 30A$	-	6.5	-	V

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} Pulsed

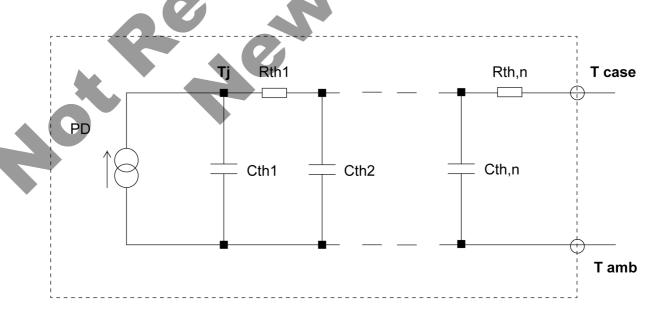
●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Cymbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	I _S *1	T - 25°C	-	-	30	Α
Pulse forward current	I _{SP} *2	T _C = 25°C	-	-	90	A
Forward voltage	V _{SD} *3	$V_{GS} = 0V, I_{S} = 30A$	-	` \	1.5	V
Reverse recovery time	t _{rr} *3		-	90	-	ns
Reverse recovery charge	Q _{rr} *3	$I_S = 30A, V_{GS} = 0V$ di/dt = 100A/µs		285	-	nC
Peak reverse recovery current	I _{rrm} *3	1007 Vµ0		-	-	Α

Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	0.3645	
R _{th2}	10.53	K/W
R _{th3}	25.75) `

Symbol	Value	Unit
C _{th1}	0.05205	
C _{th2}	0.657	Ws/K
C _{th3}	1.244	



• Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

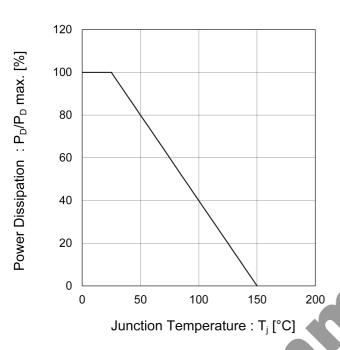


Fig.2 Maximum Safe Operating Area

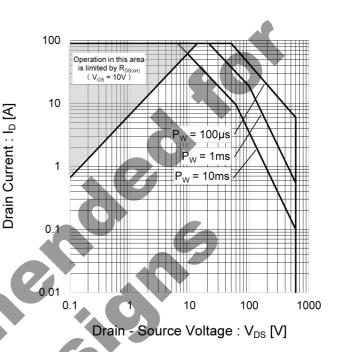


Fig.3 Drain Current Derating
Curve vs. Ambient Temperature

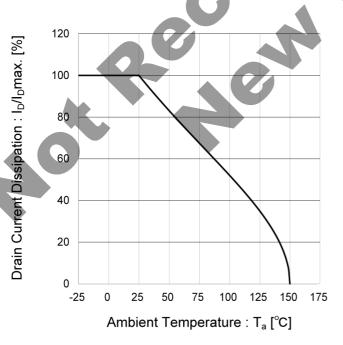
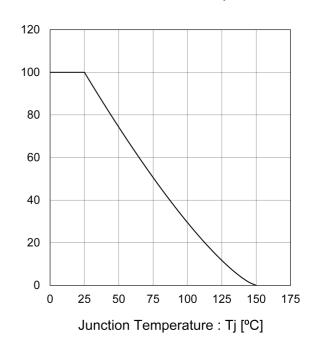


Fig.4 Avalanche Energy Derating
Curve vs. Junction Temperature



Avalanche Energy : E_{AS} / E_{AS} max. [%]

• Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

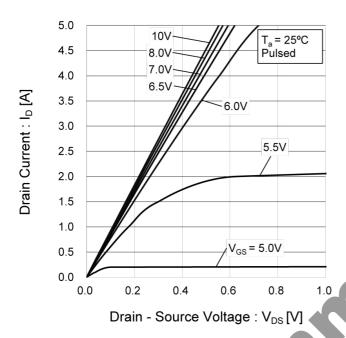


Fig.6 Typical Output Characteristics(II)

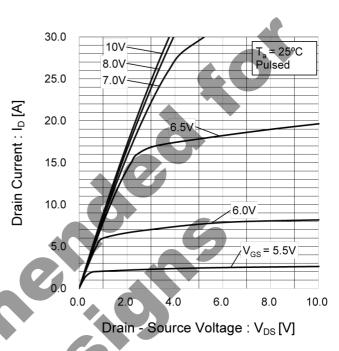


Fig.7 Normalized Breakdown Voltage vs. Junction Temperature

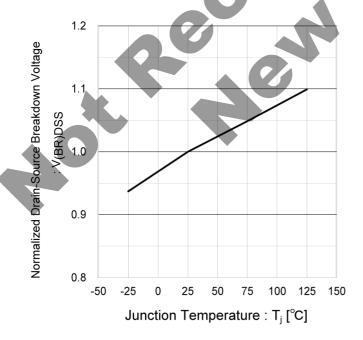
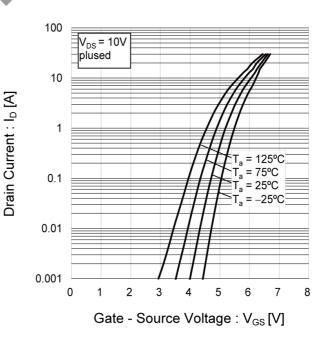


Fig.8 Typical Transfer Characteristics



Electrical characteristic curves

Fig.9 Normalized Gate Threshold Voltage. vs Junction Temperature

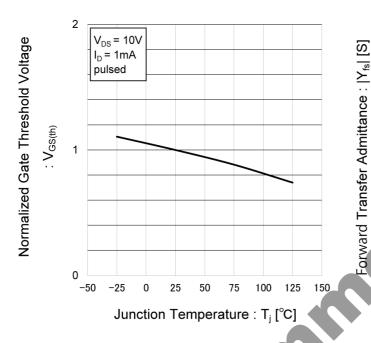


Fig.10 Forward Transfer Admittance vs.
Drain Current

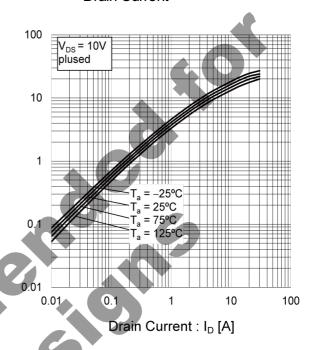
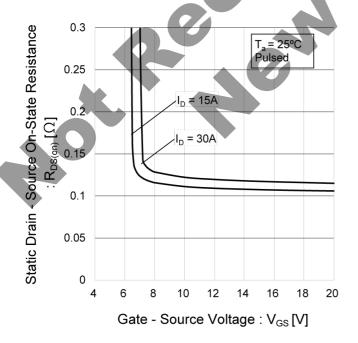
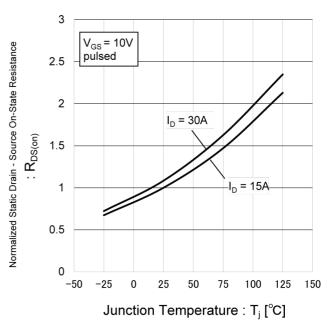


Fig.11 Static Drain - Source On - State Resistance vs. Gate Source Voltage



rig.12 Normalized Static Drain - Source On - State Resistance vs. Junction Temperature



• Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)

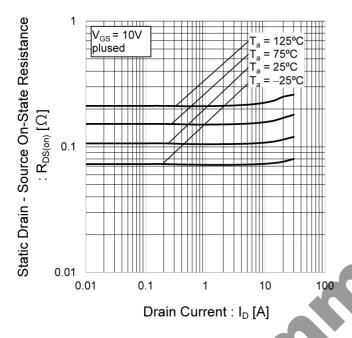


Fig.14 Typical Capacitance vs.
Drain - Source Voltage

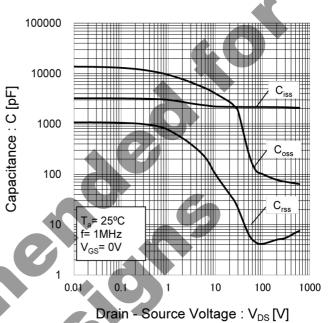


Fig.15 Switching Characteristics

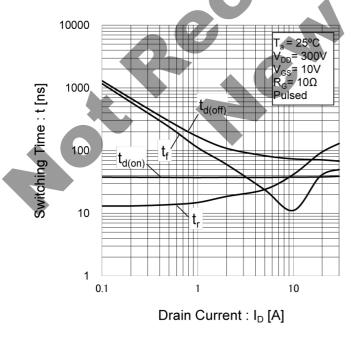
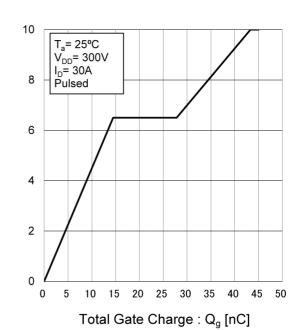


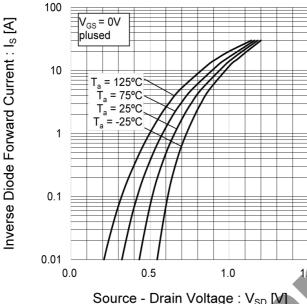
Fig.16 Dynamic Input Characteristics



Gate - Source Voltage : V_{GS} [V]

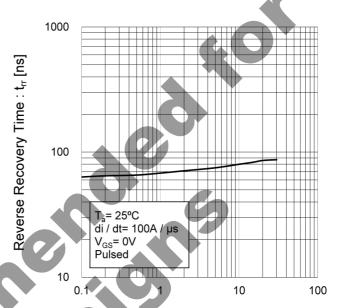
Electrical characteristic curves

Fig.17 Inverse Diode Forward Current vs. Source - Drain Voltage



Source - Drain Voltage : V_{SD} [V]

Fig.18 Reverse Recovery Time vs. Inverse Diode Forward Current



Inverse Diode Forward Current: Is [A]



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

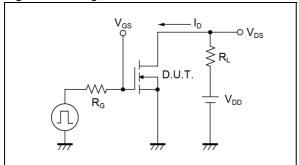


Fig.2-1 Gate Charge Measurement Circuit

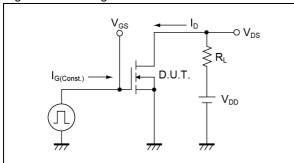


Fig.3-1 Avalanche Measurement Circuit

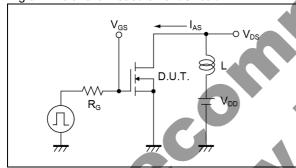


Fig.4-1 dv/dt Measurement Circuit

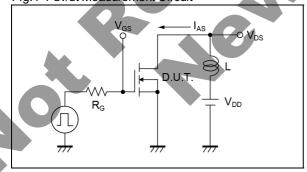


Fig.5-1 di/dt Measurement Circuit

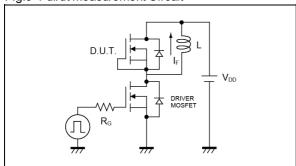


Fig.1-2 Switching Waveforms

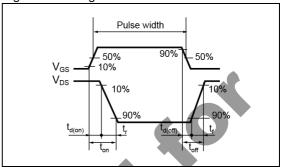


Fig.2-2 Gate Charge Waveform

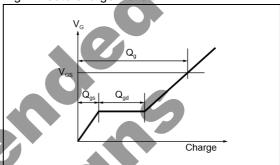


Fig.3-2 Avalanche Waveform

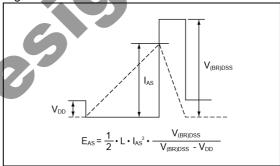


Fig.4-2 dv/dt Waveform

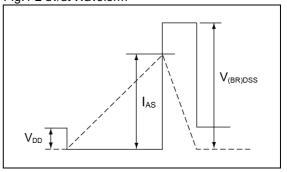
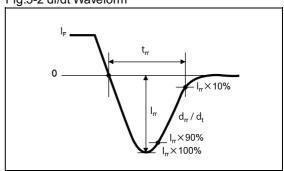
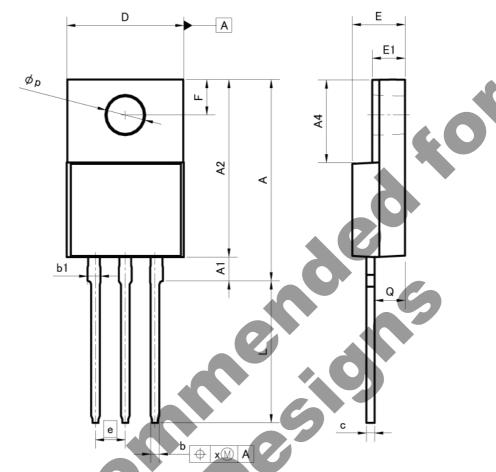


Fig.5-2 di/dt Waveform



Dimensions





DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
A	16.60	17.60	0.654	0.693	
A1	1.80	2.20	0.071	0.087	
A2	14.80	15.40	0.583	0.606	
A4	6.80	7.20	0.268	0.283	
b	0.70	0.90	0.028	0.035	
b1	1.10	1.50	0.043	0.059	
С	0.70	0.85	0.028	0.033	
D	9.90	10.30	0.390	0.406	
E	4.40	4.80	0.173	0.189	
е	2.	54	0.100		
E1	2.70	3.00	0.106	0.118	
F	2.80	3.20	0.110	0.126	
L	11.50	12.50	0.453	0.492	
р	3.00	3.40	0.118	0.134	
Q	2.10	3.10	0.083	0.122	
х	_	0.38	_	0.015	

Dimension in mm/inches



Notice

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JAPAN	USA	EU	CHINA
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CLASSIV	CLASSⅢ	CLASSⅢ	CLASSII

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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power, exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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